

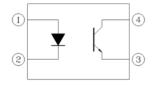
EL357N-G Series

Features:

- Halogens free
- Current transfer ratio (CTR: 50~600% at I_F =5mA, V_{CE} =5V)
- High isolation voltage between input and output (Viso=3750 V rms)
- Compact 4 Pin SOP with a 2.0 mm profile
- Pb free and RoHS compliant.
- UL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CSA approved (No. 1408633)



Schematic



Description

The EL357N-G series contains an infrared emitting diode, optically coupled to a phototransistor detector.

The devices in a 4-pin small outline SMD package.

Applications

- DC-DC Converters
- Programmable controllers
- Telecommunication equipments
- Signal transmission between circuits of different potentials and impedances

Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

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EL357N-G Series

Absolute Maximum Ratings (T_a=25°C)

	Parameter	Symbol	Rating	Unit
	Forward current	l _F	50	mA
	Peak forward current (1us, pulse)	I _{FP}	1	А
Input	Reverse voltage	V_{R}	6	V
Прис	Power dissipation		70	mW
	Derating factor (about Ta=100°C)	P_D	2.9	mW/°C
	Power dissipation	_	150	mW
	Derating factor (about Ta=80°C)	P _C	3.7	mW/°C
Output	Collector current	I _C	80	mA
	Collector-Emitter voltage	$V_{\sf CEO}$	80	V
	Emitter-Collector voltage	$V_{\sf ECO}$	7	V
Total power dissipation		P _{TOT}	200	mW
Isolation voltage *1		V_{ISO}	3750	V rms
Operating	temperature	T _{OPR}	-55 ~ +110	°C
Storage temperature		T _{STG}	-55 ~ +125	°C
Soldering	temperature *2	T _{SOL}	260	°C

<u>Notes</u>

^{*1} AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1 & 2 are shorted together, and pins 3 & 4 are shorted together.

^{*2} For 10 seconds.



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Electrical Characteristics (T_a=25°C unless specified otherwise) Input

Parameter	Symbol	Min.	Тур.*	Max.	Unit	Condition
Forward voltage	V _F	-	1.2	1.4	V	I _F = 20mA
Reverse current	I _R	-	-	10	μA	$V_R = 4V$
Input capacitance	C _{in}	1	30	250	pF	V = 0, f = 1kHz

Output

Parameter	Symbol	Min.	Тур.*	Max.	Unit	Condition
Collector-Emitter dark current	I _{CEO}	-	-	100	nA	V _{CE} = 20V, I _F = 0mA
Collector-Emitter breakdown voltage	BV _{CEO}	80	-	-	V	I _C = 0.1mA
Emitter-Collector breakdown voltage	BV _{ECO}	7	-	-	V	I _E = 0.01mA

Transfer Characteristics (T_a=25°C unless specified otherwise)

Parameter		Symbol	Min.	Тур.*	Max.	Unit	Condition	
	EL357N	CTR	50	-	600	%		
	EL357NA		80	-	160			
	EL357NB		130	-	260		I _F = 5mA ,V _{CE} = 5V	
Current Transfer ratio	EL357NC		200	-	400			
	EL357ND		300	-	600			
	EL357NE		100	-	200			
	EL357NF		150	-	300			
Collector-Emitter saturation voltage		V _{CE(sat)}	-	0.1	0.2	V	I _F = 20mA ,I _C = 1mA	
Isolation resistance		R _{IO}	5×10 ¹⁰	-	-	Ω	V _{IO} = 500Vdc, 40~60% R.H.	
Floating capacitance		C _{IO}	-	0.6	1.0	pF	$V_{IO} = 0$, $f = 1MHz$	
Cut-off frequency		fc	-	80	-	kHz	$V_{CE} = 5V$, $I_C = 2mA$ $R_L = 100\Omega$, -3dB	
Rise time		t _r	-	3	18	μs	$V_{CE} = 2V, I_{C} = 2mA,$	
Fall time		t _f	-	4	18	μs	$R_L = 100\Omega$	

^{*} Typical values at T_a = 25°C



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Typical Performance Curves

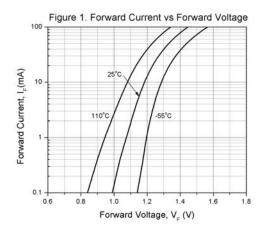


Figure 2. Normalized Collector Current vs
Forward Current

10

V_{ce}=10V

V_{ce}=5V

V_{ce}=0.4V

10

T_A=25°C

Normalized to I_p=5mA,V_{ce}=5V

Forward Current, I_F (mA)

Figure 3. Normalized Current Transfer Ratio vs
Forward Current

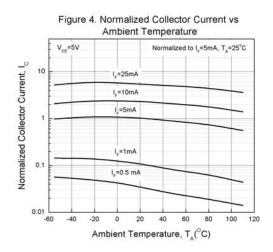
T_x=25°C

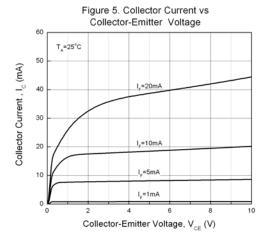
Normalized to I_r=5mA,V_{CE}=5V

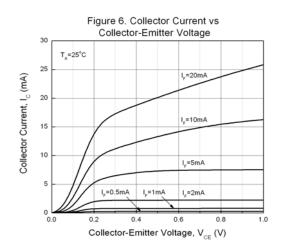
V_{CE}=10V

V_{CE}=0.4V

Forward Current, IF (mA)

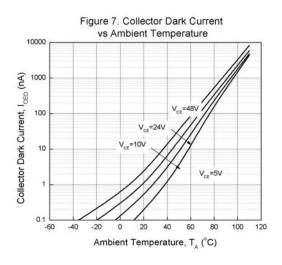


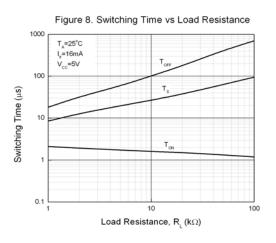


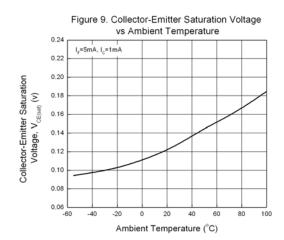




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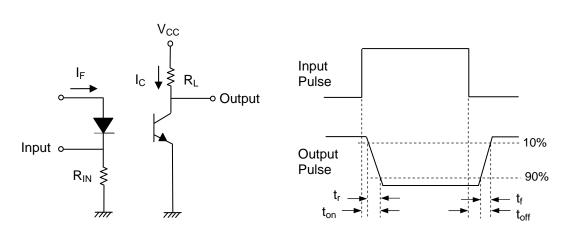


Figure 10. Switching Time Test Circuit & Waveforms



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Order Information

Part Number

EL357NX(Y)-VG

Note

357N = Part No.

X = CTR Rank (A, B, C, D, E, For none) Y = Tape and reel option (TA, TB or none).

V = VDE (optional) G = Halogen free

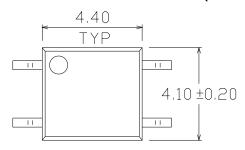
Option	Description	Packing quantity
None	Standard SMD option	100 units per tube
-V	Standard SMD option + VDE	100 units per tube
(TA)	TA Tape & reel option	3000 units per reel
(TB)	TB Tape & reel option	3000 units per reel
(TA)-V	TA Tape & reel option + VDE	3000 units per reel
(TB)-V	TB Tape & reel option + VDE	3000 units per reel

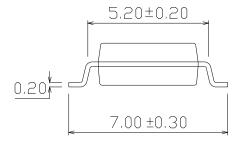


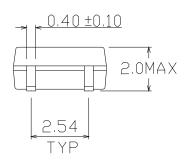
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Package Drawing

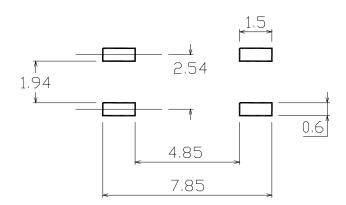
(Dimensions in mm)







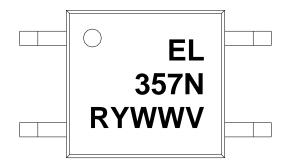
Recommended pad layout for surface mount leadform





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Device Marking



Notes

EL denotes Everlight 357N denotes Device Number

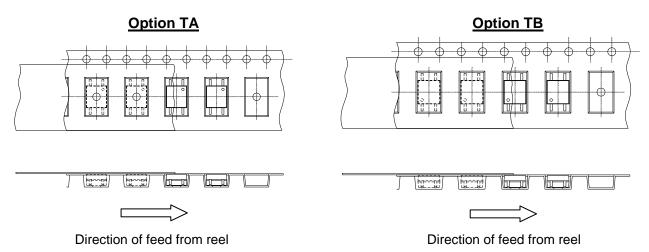
R denotes CTR Rank (A, B, C, D, E, F or none)

Y denotes 1 digit Year code WW denotes 2 digit Week code V denotes VDE (optional)

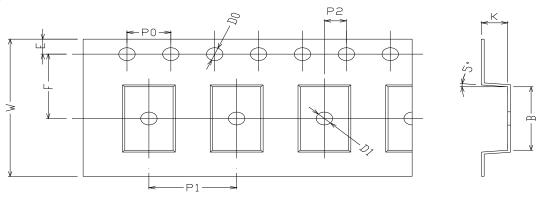


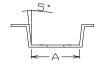
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Tape & Reel Packing Specifications



Tape dimensions



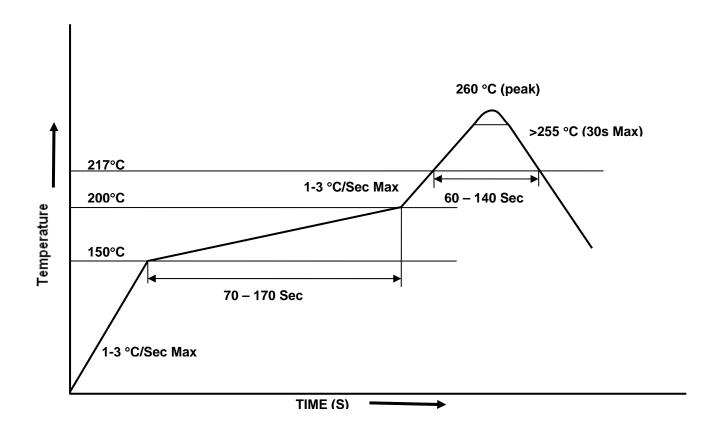


Dimension No.	Α	В	Do	D1	E	F
Dimension (mm)	4.4 ± 0.1	7.4 ± 0.1	1.5 + 0.1/-0	1.5 ± 0.1	1.7 5± 0.1	7.5 ± 0.1
Dimension No.	Po	P1	P2	t	W	К



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Solder Reflow Temperature Profile





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